

RELIABILITY REPORT FOR MAX15091ETI+T / MAX15091AETI+T PLASTIC ENCAPSULATED DEVICES

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MAXIM INTEGRATED

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Conclusion

The MAX15091ETI+T / MAX15091AETI+T successfully meets the quality and reliability standards required of all Maxim Integrated products. In addition, Maxim Integrated's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim Integrated's quality and reliability standards.

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I. Device Description

A. General

The MAX15091/MAX15091A ICs are integrated solutions for hot-swap applications requiring the safe insertion and removal of circuit line cards from a live backplane. The devices integrate a hot-swap controller, 18m (typ) power MOSFET, and an electronic circuit-breaker protection in a single package. The devices integrate an accurate current-sense circuitry and provide 170μ A/A of proportional output current. The devices are designed for protection of 2.7V to 18V supply voltages. These devices implement a foldback current limit during startup to control inrush current lowering di/dt and keep the MOSFET operating under safe operating area (SOA) conditions. After the startup cycle is complete, on-chip comparators provide VariableSpeed/BiLevel(tm) protection against short-circuit and overcurrent faults, and immunity against system noise and load transients. The load is disconnected in the event of a fault condition. The devices are factory calibrated to deliver accurate overcurrent protection with ±10% accuracy. During a fault condition, the MAX15091 latches off, while the MAX15091A enters autoretry mode. The devices feature an IN to OUT short-circuit detection before startup. The devices provide a power-MOSFET GATE pin to program the slew rate during startup by adding an external capacitor. The devices have overvoltage/undervoltage input pins that can detect an overvoltage/undervoltage fault and disconnect the IN from the OUT. Additional features include internal overtemperature protection, power-good output, and fault-indicator output. The MAX15091/MAX15091A are available in a 28-pin, 5mm × 5mm TQFN power package and are rated over the -40°C to +85°C extended temperature range.



2.7V to 18V, 9A, Integrated Hot-Swap Solution with Current Report Output

II. Manufacturing Information

- A. Description/Function:
- B. Process:
- C. Number of Device Transistors:
- D. Fabrication Location:
- E. Assembly Location:
- F. Date of Initial Production: March 25, 2013

III. Packaging Information

A. Package Type: 2	28-pin TQFN 5x5
B. Lead Frame: 0	Copper
C. Lead Finish:	100% matte Tin
D. Die Attach:	Conductive
E. Bondwire:	Au (1.3 mil dia.)
F. Mold Material:	Epoxy with silica filler
G. Assembly Diagram: #	#05-9000-5236
H. Flammability Rating:	Class UL94-V0
I. Classification of Moisture Sensitivity I per JEDEC standard J-STD-020-C	Level 1
J. Single Layer Theta Ja:	47°C/W
K. Single Layer Theta Jc:	2°C/W
L. Multi Layer Theta Ja: 2	29°C/W
M. Multi Layer Theta Jc: 2	2°C/W

S18

11259

China, Taiwan and Thailand

USA

IV. Die Information

A. Dimensions:		140.1574 X 82.6771 mils
B. Passivation:		Si ₃ N ₄ /SiO ₂ (Silicon nitride/ Silicon dioxide)
C. Interconnect:		Al/0.5%Cu with Ti/TiN Barrier
D. Backside Metallizat	ion:	None
E. Minimum Metal Wid	lth:	0.23 microns (as drawn)
F. Minimum Metal Spa	icing:	0.23 microns (as drawn)
G. Bondpad Dimensio	ns:	
H. Isolation Dielectric:		SiO ₂
I. Die Separation Met	nod:	Wafer Saw



V. Quality Assurance Information

A. Quality Assurance Contacts:	Richard Aburano (Manager, Reliability Engineering) Don Lipps (Manager, Reliability Engineering) Bryan Preeshl (Vice President of QA)
B. Outgoing Inspection Level:	0.1% for all electrical parameters guaranteed by the Datasheet. 0.1% for all Visual Defects.
C. Observed Outgoing Defect Rate:	< 50 ppm
D. Sampling Plan:	Mil-Std-105D

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in Table 1. Using these results, the Failure Rate (λ) is calculated as follows:

$$\frac{\lambda}{MTTF} = \frac{1}{102 \times 4340 \times 80 \times 2}$$
(Chi square value for MTTF upper limit)
(where 4340 = Temperature Acceleration factor assuming an activation energy of 0.8eV)

$$\lambda = 13.7 \times 10^{-9}$$

𝒫 = 13.7 F.I.T. (60% confidence level @ 25°C)

The following failure rate represents data collected from Maxim Integrated's reliability monitor program. Maxim Integrated performs quarterly life test monitors on its processes. This data is published in the Reliability Report found at http://www.maximintegrated.com/qa/reliability/monitor. Cumulative monitor data for the S18 Process results in a FIT Rate of 0.05 @ 25°C and 0.93 @ 55°C (0.8 eV, 60% UCL)

B. E.S.D. and Latch-Up Testing (lot SAIV5Q001B, D/C 1233)

The NQ90-1 die type has been found to have all pins able to withstand a HBM transient pulse of +/-2500V per JEDEC JESD22-A114. Latch-Up testing has shown that this device withstands a current of +/-100mA and overvoltage per JEDEC JESD78.



Table 1 Reliability Evaluation Test Results

MAX15091ETI+T / MAX15091AETI+T

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	SAMPLE SIZE	NUMBER OF FAILURES	COMMENTS
Static Life Test (N	Note 1)				
	Ta = 135°C	DC Parameters	80	0	SAIV5Q001C, D/C 1233
	Biased	& functionality			
	Time = 192 hrs.				

Note 1: Life Test Data may represent plastic DIP qualification lots.